

## S9012 TRANSISTOR (PNP)

### FEATURES

- Complementary to S9013
- Excellent  $h_{FE}$  linearity

### MAXIMUM RATINGS ( $T_A=25^{\circ}\text{C}$ unless otherwise noted)

| Symbol    | Parameter                     | Value   | Units              |
|-----------|-------------------------------|---------|--------------------|
| $V_{CBO}$ | Collector-Base Voltage        | -40     | V                  |
| $V_{CEO}$ | Collector-Emitter Voltage     | -25     | V                  |
| $V_{EBO}$ | Emitter-Base Voltage          | -5      | V                  |
| $I_C$     | Collector Current -Continuous | -500    | mA                 |
| $P_C$     | Collector Power Dissipation   | 625     | mW                 |
| $T_J$     | Junction Temperature          | 150     | $^{\circ}\text{C}$ |
| $T_{stg}$ | Storage Temperature           | -55-150 | $^{\circ}\text{C}$ |

### TO-92

1. EMITTER
2. BASE
3. COLLECTOR

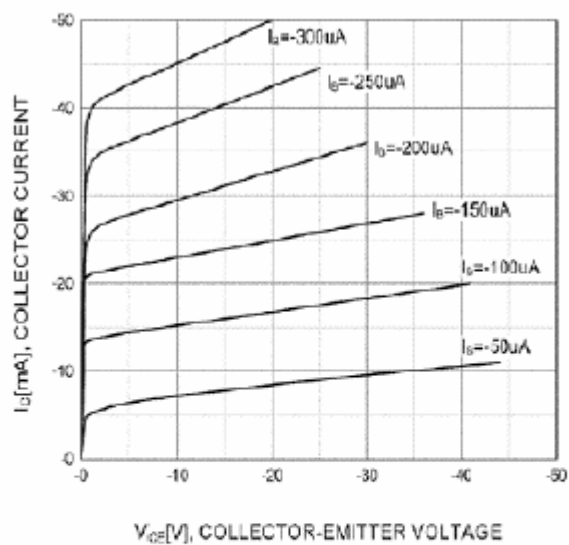


### ELECTRICAL CHARACTERISTICS ( $T_{amb}=25^{\circ}\text{C}$ unless otherwise specified)

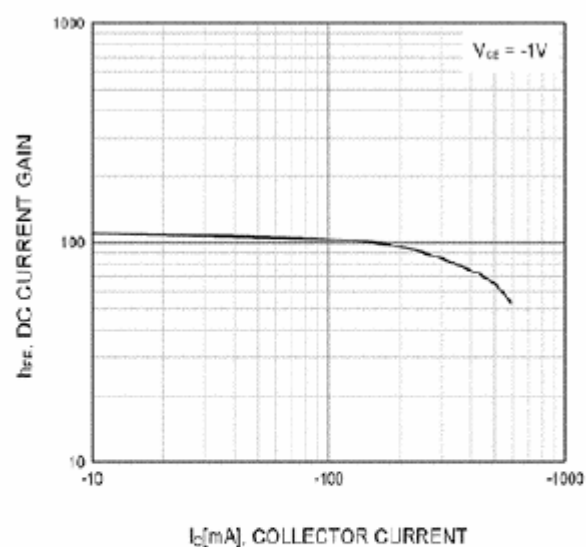
| Parameter                            | Symbol        | Test conditions                                                 | MIN | TYP | MAX  | UNIT          |
|--------------------------------------|---------------|-----------------------------------------------------------------|-----|-----|------|---------------|
| Collector-base breakdown voltage     | $V_{(BR)CBO}$ | $I_C = -100\mu\text{A}, I_E = 0$                                | -40 |     |      | V             |
| Collector-emitter breakdown voltage  | $V_{(BR)CEO}$ | $I_C = -1\text{mA}, I_B = 0$                                    | -25 |     |      | V             |
| Emitter-base breakdown voltage       | $V_{(BR)EBO}$ | $I_E = -100\mu\text{A}, I_C = 0$                                | -5  |     |      | V             |
| Collector cut-off current            | $I_{CBO}$     | $V_{CB} = -40\text{V}, I_E = 0$                                 |     |     | -0.1 | $\mu\text{A}$ |
| Collector cut-off current            | $I_{CEO}$     | $V_{CE} = -20\text{V}, I_B = 0$                                 |     |     | -0.1 | $\mu\text{A}$ |
| Emitter cut-off current              | $I_{EBO}$     | $V_{EB} = -5\text{V}, I_C = 0$                                  |     |     | -0.1 | $\mu\text{A}$ |
| DC current gain                      | $h_{FE(1)}$   | $V_{CE} = -4\text{V}, I_C = -1\text{mA}$                        | 64  |     | 400  |               |
|                                      | $h_{FE(2)}$   | $V_{CE} = -1\text{V}, I_C = -500\text{mA}$                      | 40  |     |      |               |
| Collector-emitter saturation voltage | $V_{CE(sat)}$ | $I_C = -500\text{mA}, I_B = -50\text{mA}$                       |     |     | -0.6 | V             |
| Base-emitter saturation voltage      | $V_{BE(sat)}$ | $I_C = -500\text{mA}, I_B = -50\text{mA}$                       |     |     | -1.2 | V             |
| Transition frequency                 | $f_T$         | $V_{CE} = -6\text{V}, I_C = -20\text{mA}$<br>$f = 30\text{MHz}$ | 150 |     |      | MHz           |

### CLASSIFICATION OF $h_{FE(1)}$

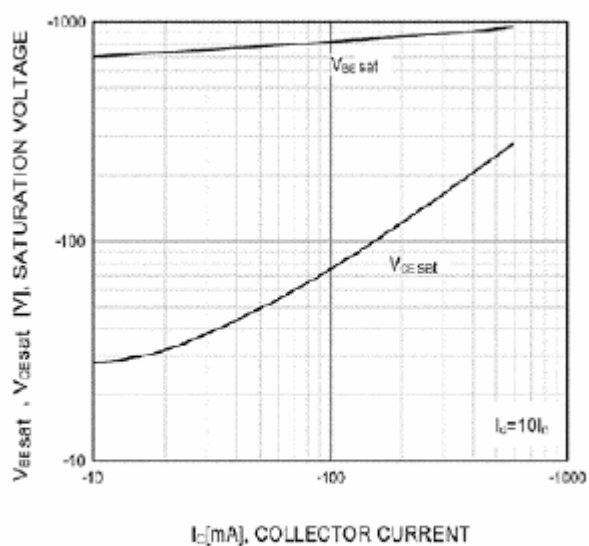
| Rank  | D     | E      | F      | G       | H       | I       | J       |
|-------|-------|--------|--------|---------|---------|---------|---------|
| Range | 64-91 | 78-112 | 96-135 | 112-166 | 144-202 | 190-300 | 300-400 |



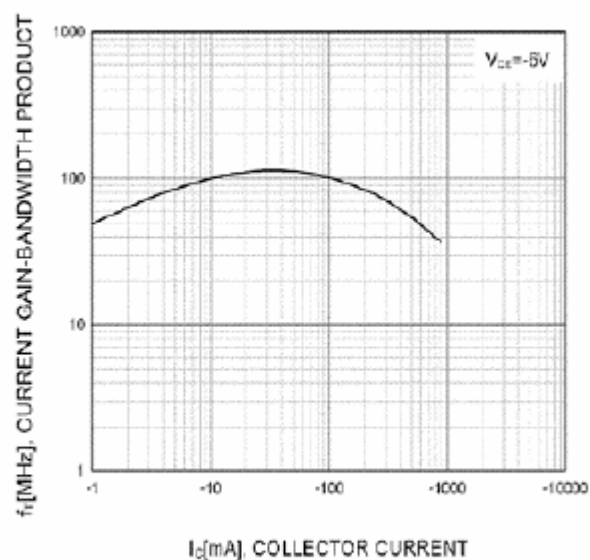
Static Characteristic



DC current Gain



Base-Emitter Saturation Voltage  
Collector-Emitter Saturation Voltage



Current Gain Bandwidth Product